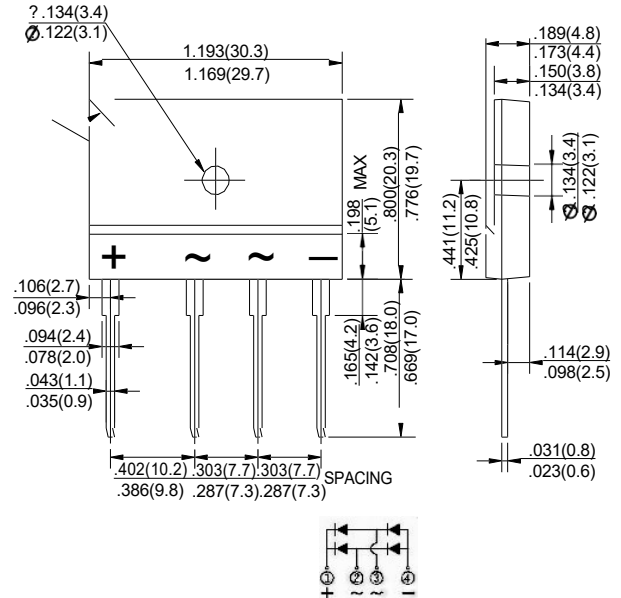


SILICON BRIDGE RECTIFIERS

Features

- ◆ Rating to 1000V prv
- ◆ deal for printed circuit board
- ◆ Reliable low cost construction utilizing molded plastic
- ◆ technique Plastic material has U/L lammability classification 94V-0
- ◆ Low forward voltage drop,high current capability

GBJ



Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	GBJ25005	GBJ2501	GBJ2502	GBJ2504	GBJ2506	GBJ2508	GBJ2510	UNITS
Marking Code									
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward (with heatsink NOTE 2) Rectified current @ $T_c=100^\circ\text{C}$ (without heatsink)	I_{AV}	25.0 4.2							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	350							A
Rating for Fusing ($t < 8.3\text{ms}$)	I^2t	510							A^2s
Maximum forward voltage at 12.5A DC	V_F	1.0							V
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	I_R	10							μA
		0.5							mA
Typical Junction Capacitance (Note 1)	C_J	85							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	1.0							$^\circ\text{C/W}$
Operating junction temperature range	T_J	-55 to +150							$^\circ\text{C}$
storage temperature range	T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. Device mounted on 250mm x 250mm x 20mm aluminum plate heatsink.

3. The typical data above is for reference only.

Ratings And Characteristic Curves

Fig. 1 Derating Curve for Output Rectified Current

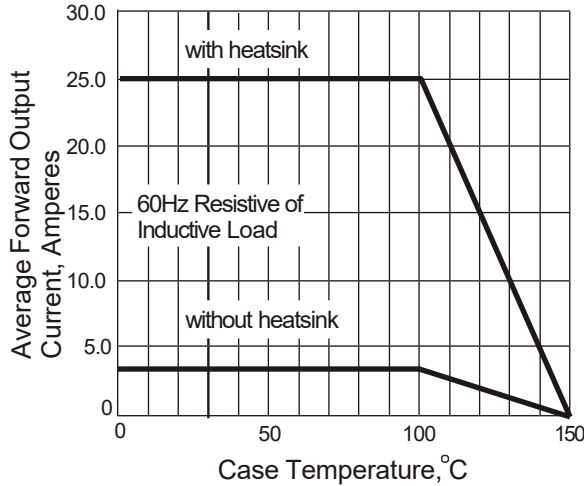


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

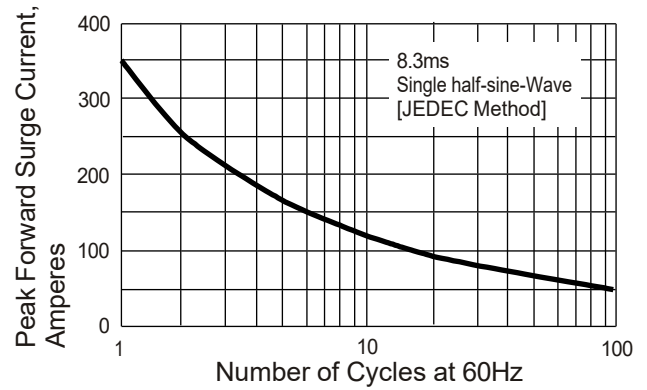


Fig. 3 Typical Instantaneous Forward Characteristics

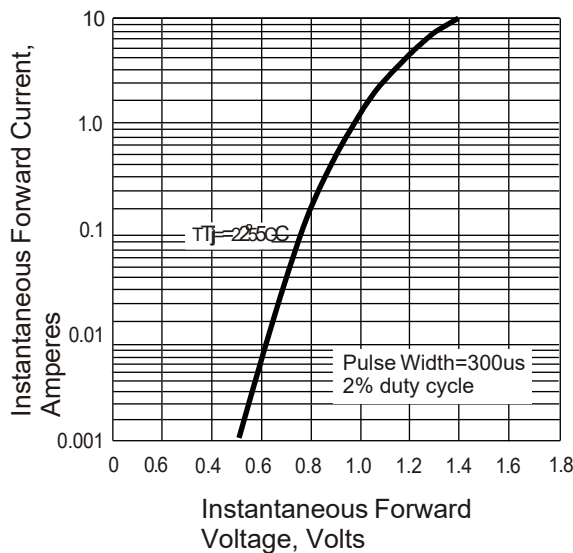


Fig. 4 Typical Reverse Characteristics at $T_J = 25^\circ\text{C}$

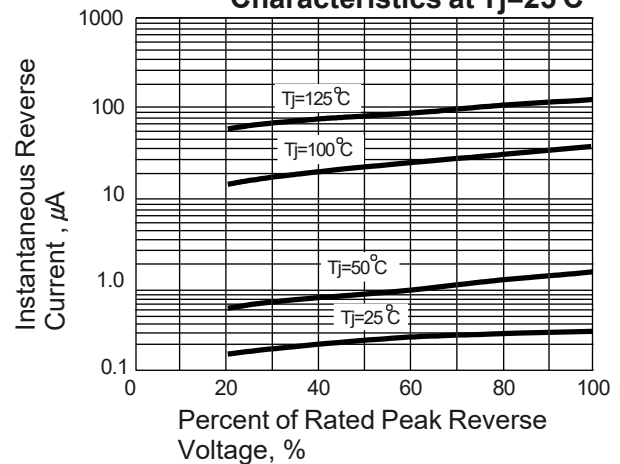
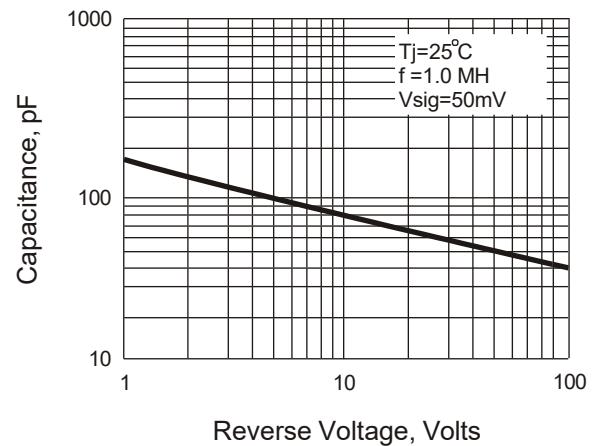


Fig. 5 Typical Junction Capacitance



The curve above is for reference only.